

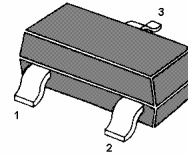
MMUN2211...MMUN2241

NPN Silicon Epitaxial Planar Transistor

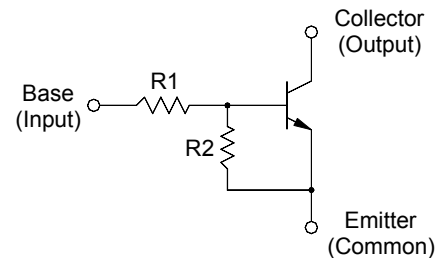
for switching and interface circuit and drive circuit applications

Resistor Values

Type	R1 (K)	R2 (K)
MMUN2211	10	10
MMUN2212	22	22
MMUN2213	47	47
MMUN2214	10	47
MMUN2215	10	∞
MMUN2216	4.7	∞
MMUN2230	1	1
MMUN2231	2.2	2.2
MMUN2232	4.7	4.7
MMUN2233	4.7	47
MMUN2234	22	47
MMUN2235	2.2	47
MMUN2238	2.2	∞
MMUN2241	100	∞

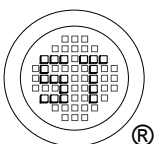


1. Base 2. Emitter 3. Collector
SOT-23 Plastic Package



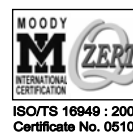
Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	50	V
Collector Emitter Voltage	V_{CEO}	50	V
Collector Current	I_C	100	mA
Total Power Dissipation	P_{tot}	200	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_s	- 55 to + 150	$^\circ\text{C}$



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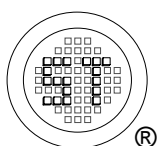


Dated : 17/08/2007

MMUN2211...MMUN2241

Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit	
DC Current Gain at $V_{CE} = 10\text{ V}$, $I_C = 5\text{ mA}$	MMUN2211	h_{FE}	35	-	-
	MMUN2212	h_{FE}	60	-	-
	MMUN2213	h_{FE}	80	-	-
	MMUN2214	h_{FE}	80	-	-
	MMUN2215	h_{FE}	160	-	-
	MMUN2216	h_{FE}	160	-	-
	MMUN2230	h_{FE}	3	-	-
	MMUN2231	h_{FE}	8	-	-
	MMUN2232	h_{FE}	15	-	-
	MMUN2233	h_{FE}	80	-	-
	MMUN2234	h_{FE}	80	-	-
	MMUN2235	h_{FE}	80	-	-
	MMUN2238	h_{FE}	160	-	-
	MMUN2241	h_{FE}	160	-	-
Collector Base Cutoff Current at $V_{CB} = 50\text{ V}$	I_{CBO}	-	100	nA	
Collector Emitter Cutoff Current at $V_{CE} = 50\text{ V}$	I_{CEO}	-	500	nA	
Emitter Base Cutoff Current at $V_{EB} = 6\text{ V}$	MMUN2211	I_{EBO}	-	0.5	mA
	MMUN2212	I_{EBO}	-	0.2	mA
	MMUN2213	I_{EBO}	-	0.1	mA
	MMUN2214	I_{EBO}	-	0.2	mA
	MMUN2215	I_{EBO}	-	0.9	mA
	MMUN2216	I_{EBO}	-	1.9	mA
	MMUN2230	I_{EBO}	-	4.3	mA
	MMUN2231	I_{EBO}	-	2.3	mA
	MMUN2232	I_{EBO}	-	1.5	mA
	MMUN2233	I_{EBO}	-	0.18	mA
	MMUN2234	I_{EBO}	-	0.13	mA
	MMUN2235	I_{EBO}	-	0.2	mA
	MMUN2238	I_{EBO}	-	4	mA
	MMUN2241	I_{EBO}	-	0.1	mA
Collector Base Breakdown Voltage at $I_C = 10\text{ }\mu\text{A}$	$V_{(BR)CBO}$	50	-	V	
Collector Emitter Breakdown Voltage at $I_C = 2\text{ mA}$	$V_{(BR)CEO}$	50	-	V	
Collector Emitter Saturation Voltage at $I_C = 10\text{ mA}$, $I_B = 0.3\text{ mA}$ at $I_C = 10\text{ mA}$, $I_B = 5\text{ mA}$ at $I_C = 10\text{ mA}$, $I_B = 1\text{ mA}$	MMUN2230	V_{CEsat}	-	0.25	V
	MMUN2231	V_{CEsat}	-	0.25	V
	MMUN2215	V_{CEsat}	-	0.25	V
	MMUN2216	V_{CEsat}	-	0.25	V
	MMUN2232	V_{CEsat}	-	0.25	V
	MMUN2233	V_{CEsat}	-	0.25	V
	MMUN2234	V_{CEsat}	-	0.25	V
	MMUN2235	V_{CEsat}	-	0.25	V
	MMUN2238	V_{CEsat}	-	0.25	V
	MMUN2241	V_{CEsat}	-	0.25	V



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ISO/TS 16949:2002
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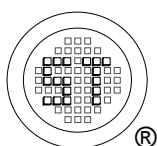
ISO 9001:2000
Certificate No. 0506098

Dated : 17/08/2007

MMUN2211...MMUN2241

Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit		
Output Voltage (on) at $V_{CC} = 5\text{ V}$, $V_B = 2.5\text{ V}$, $R_L = 1\text{ K}\Omega$	MMUN2211	V_{OL}	-	0.2	V	
	MMUN2212	V_{OL}	-	0.2	V	
	MMUN2214	V_{OL}	-	0.2	V	
	MMUN2215	V_{OL}	-	0.2	V	
	MMUN2216	V_{OL}	-	0.2	V	
	MMUN2230	V_{OL}	-	0.2	V	
	MMUN2231	V_{OL}	-	0.2	V	
	MMUN2232	V_{OL}	-	0.2	V	
	MMUN2233	V_{OL}	-	0.2	V	
	MMUN2234	V_{OL}	-	0.2	V	
	MMUN2235	V_{OL}	-	0.2	V	
	MMUN2238	V_{OL}	-	0.2	V	
	at $V_{CC} = 5\text{ V}$, $V_B = 3.5\text{ V}$, $R_L = 1\text{ K}\Omega$	MMUN2213	V_{OL}	-	0.2	V
	at $V_{CC} = 5\text{ V}$, $V_B = 5\text{ V}$, $R_L = 1\text{ K}\Omega$	MMUN2241	V_{OL}	-	0.2	V
	Output Voltage (off) at $V_{CC} = 5\text{ V}$, $V_B = 0.5\text{ V}$, $R_L = 1\text{ K}\Omega$ at $V_{CC} = 5\text{ V}$, $V_B = 0.05\text{ V}$, $R_L = 1\text{ K}\Omega$ at $V_{CC} = 5\text{ V}$, $V_B = 0.25\text{ V}$, $R_L = 1\text{ K}\Omega$	MMUN2230	V_{OH}	4.9	-	V
		MMUN2215	V_{OH}	4.9	-	V
MMUN2216		V_{OH}	4.9	-	V	
MMUN2233		V_{OH}	4.9	-	V	
MMUN2238		V_{OH}	4.9	-	V	
MMUN2235		V_{OH}	4.9	-	V	
Input Resistor	MMUN2211	R1	7	13	K Ω	
	MMUN2212	R1	15.4	28.6	K Ω	
	MMUN2213	R1	32.9	61.1	K Ω	
	MMUN2214	R1	7	13	K Ω	
	MMUN2215	R1	7	13	K Ω	
	MMUN2216	R1	3.3	6.1	K Ω	
	MMUN2230	R1	0.7	1.3	K Ω	
	MMUN2231	R1	1.5	2.9	K Ω	
	MMUN2232	R1	3.3	6.1	K Ω	
	MMUN2233	R1	3.3	6.1	K Ω	
	MMUN2234	R1	15.4	28.6	K Ω	
	MMUN2235	R1	1.54	2.86	K Ω	
	MMUN2238	R1	1.54	2.88	K Ω	
	MMUN2241	R1	70	130	K Ω	
Resistor Ratio	MMUN2211/MMUN2212/MMUN2213	R1/R2	0.8	1.2	-	
	MMUN2214	R1/R2	0.17	0.25	-	
	MMUN2215/MMUN2216/MMUN2238	R1/R2	-	-	-	
	MMUN2241	R1/R2	-	-	-	
	MMUN2230/MMUN2231/MMUN2232	R1/R2	0.8	1.2	-	
	MMUN2233	R1/R2	0.055	0.185	-	
	MMUN2234	R1/R2	0.38	0.56	-	
	MMUN2235	R1/R2	0.038	0.056	-	



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